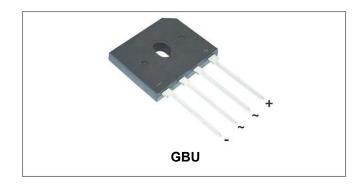






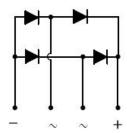
# GBU25005 THRU GBU2510 Single-Phase 25.0A Glass Passivated Bridge Rectifier



### **Features**

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Mechanical Data**

- Case: GBU, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
  - Wethou 200
- Polarity: as marked on caseMounting Position: Any
- Lead Free: For RoHS / Lead Free Version

### Maximum Ratings:@T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	GBU 25005	GBU 2501	GBU 2502	GBU 2504	GBU 2506	GBU 2508	GBU 2510	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average forward rectified output current (with heatsink) @Tc=90°C (without heatsink)		25 3.6							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	350					А		
I <sup>2</sup> t Rating for fusing (t <8.3ms)	l²t	508.357				A <sup>2</sup> s			

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## Electrical Characteristics:@TA=25°C unless otherwise specified

Type Number	Symbol	GBU 25005	GBU 2501	GBU 2502	GBU 2504	GBU 2506	GBU 2508	GBU 2510	Units
Forward Voltage (per element) @I <sub>F</sub> =12.5A	VF	V <sub>F</sub> 1.0			V				
Peak Reverse Current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>RM</sub>	5.0 200						μА	
Typical Junction Capacitance(per leg) (Note 1)	С	110						pF	

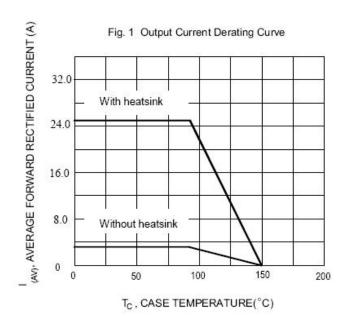
<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

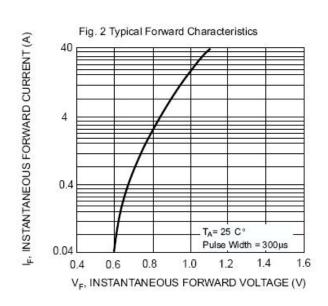
## Thermal-Mechanical Specifications:@TA=25°C unless otherwise specified

Type Number	Symbol	GBU 25005	GBU 2501	GBU 2502	GBU 2504	GBU 2506	GBU 2508	GBU 2510	Units
Typical Thermal Resistance	R <sub>0JA</sub> R <sub>0JC</sub> R <sub>0JL</sub>	8.7			°C/W				
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150				°C			

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

## **Ratings and Characteristics Curves**





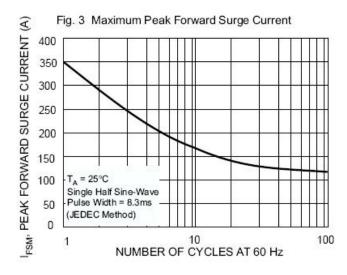
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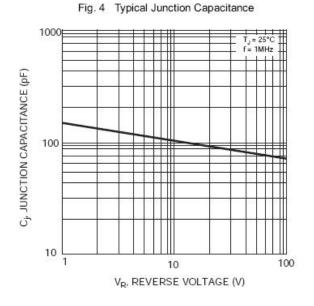
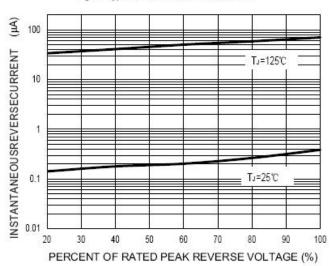


Fig. 5 Typical Reverse Characteristics







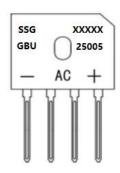


## **Ordering Information**

Device	Package	Plating	Shipping
GBU25005 THRU GBU2510	GBU (Pb-Free)	Pure Sn	20pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



 Where XXXXX is YYWWL

 SSG
 = SSG

 YY
 = Year

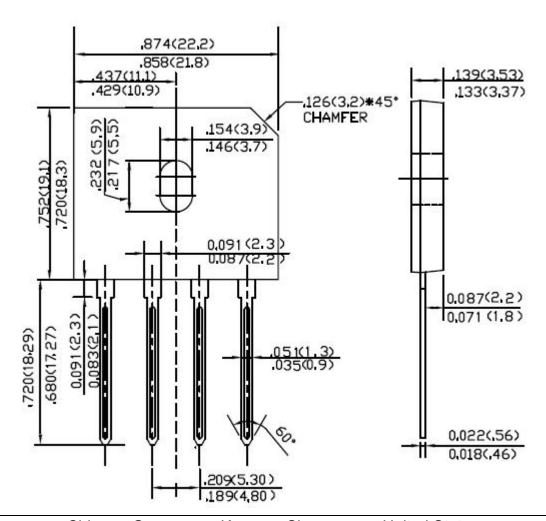
 WW
 = Week

 L
 = Lot Number

 GBU25005
 = Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Mechanical Dimensions GBU (Inches/Millimeters)**



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